NSN 5961-00-925-5104

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View Online at https://aerobasegroup.com/nsn/5961-00-925-5104 **Inclosure Material:** Metal **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 3.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 2.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 75.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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